NSN 5961-01-509-6805

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-509-6805 **Inclosure Material:** Plastic **Overall Length:** Between 8.600 millimeters and 9.100 millimeters **Terminal Length:** 24.500 millimeters **Overall Diameter:** Between 8.600 millimeters and 9.100 millimeters **End Application:** 2320-01-494-7606 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.000 breakdown voltage, dc **Current Rating Per Characteristic:** 200.000 amperes source cutoff current preset **Power Rating Per Characteristic:** 1.000 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.000 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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